

BT131

双向可控硅
TRIAC版本号
201603-A

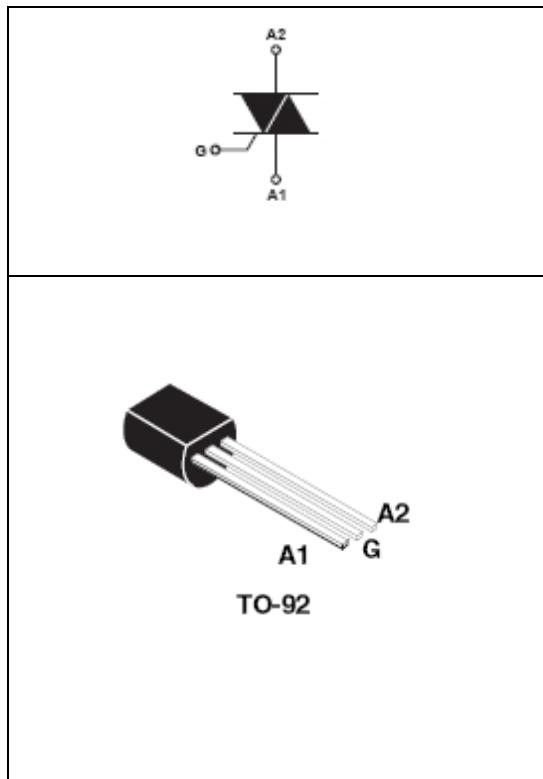
产品概述 GENERAL DESCRIPTION

BT131 双向可控硅采用穿通隔离台面结构，复合玻璃钝化PN结表面保护工艺技术，dv/dt高，可靠性高，适用于控温、调光、马达控制。

BT131 Triacs is fabricated using separation diffusion processes ,the junction termination areas are passivated with glass. Thanks to highly dv/dt and reliability,the Triacs series is suitable for domestic lighting ,heating and motor speed controllers.

主要参数 MAIN CHARACTERISTICS

参数 Parameter	数值 Value	单位 Unit
I _{T(RMS)}	1	A
V _{DRM/V_{RRM}}	600&800	V
I _{GT(IV)}	≤7	mA



产品特性 FEATURES

- dv/dt高
- 通态压降低
- RoHS环保产品
- Highly dv/dt
- Low on-state voltage
- RoHS Products

应用领域 APPLICATIONS

主要应用于调光、控温、马达控制。

domestic lighting ,heating and motor speed controllers.

极限值(除非另有规定, $T_j=25^\circ\text{C}$) ABSOLUTE RATINGS

($T_j=25^\circ\text{C}$,unless otherwise specified)

符号 Symbol	参数 Parameter		数值 Value	单位 Unit
I_{TRMS}	RMS 通态电流 RMS on-state current (full sine wave)	$T_C=90^\circ\text{C}$	1	A
I_{TSM}	通态峰值浪涌电流 Non repetitive surge peak on-state current	$F=50\text{Hz}, t=20\text{ms}$	12.5	A
I^2t	I^2t 耗散值 I^2t value for fusing	$T_P=10\text{ms}$	0.78	A^2s
di/dt	通态电流上升值 Critical rate of rise of on-state current	$F=120\text{Hz}, T_j=125^\circ\text{C}$	50	$\text{A}/\mu\text{s}$
I_{GM}	门极峰值电流 Peak gate current	$TP=20\mu\text{s}, T_j=125^\circ\text{C}$	2	A
$P_{G(AV)}$	平均门极耗散功率 Average gate power dissipation	$T_j=125^\circ\text{C}$	0.5	W
T_{stg}	贮存结温范围 Storage junction temperature range		-40~+150	°C
T_j	工作结温范围 Operating junction temperature range		-40~+125	°C

电参数(除非另有规定, $T_j=25^\circ\text{C}$) ELECTRICAL CHARACTERISTICS

($T_j=25^\circ\text{C}$,unless otherwise specified)

参数 Parameter	符号 Symbol	规范值 Value	单位 Unit	测试条件 Test Conditions
触发电流 Gate trigger current	I_{GT}	$I \sim III$	≤ 5	$V_D=12\text{V}, I_T=0.1\text{A}$
		IV	≤ 7	
触发电压 Gate trigger voltage	V_{GT}	$I \sim IV$	≤ 1.5	$V_D=12\text{V}, I_T=0.1\text{A}$
维持电流 Holding current		I_H	≤ 5	$V_D=12\text{V}, I_T=0.1\text{A}$
擎住电流 Latching current	I_L	I、III	≤ 5	$V_D=12\text{V}, I_T=0.1\text{A}$
		II、IV	≤ 8	
电压上升率 Rise of off-state voltage		dv/dt	≥ 5	$V_D=67\% V_{DRM}$
通态压降 Peak on-state voltage		V_{TM}	≤ 1.5	$I_T=2.0\text{A}$
断态漏电流 Peak repetitive forward blocking current	I_{DRM}		≤ 5	$V_{RRM}=V_{DRM}, T_j = 25^\circ\text{C}$
		I_{RRM}	≤ 0.5	$V_{RRM}=V_{DRM}, T_j = 125^\circ\text{C}$

热特性 THERMAL RESISTANCES

符号 Symbol	参数 Parameter	数值 Value	单位 Unit
$R_{th(j-c)}$	Junction to case(AC)	60	°C/W
$R_{th(j-a)}$	Junction to ambient	150	°C/W

特征曲线 ELECTRICAL CHARACTERISTICS (CURVES)

图1 最大耗散功率与RMS通态电流关系

Fig.1. Maximum Power Dissipation Versus
on-state current

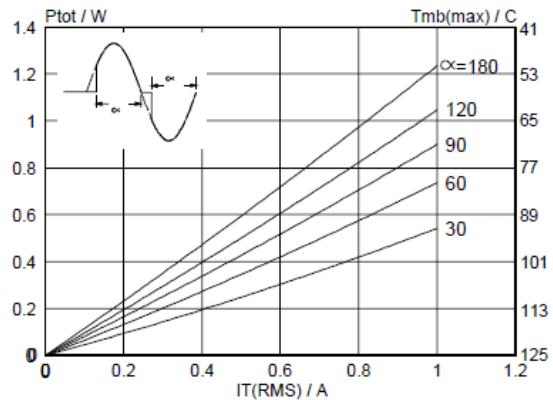


图3 通态特性

Fig.3. On-State Characteristics

图2 RMS通态电流与Tc温度关系

Fig.2. RMS On-state Current Versus TL

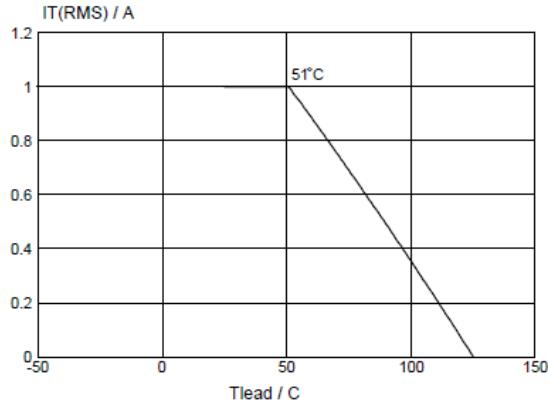


图4 通态浪涌峰值电流与周期数关系

Fig.4. Surge Peak On-state Current Versus Number Cycles

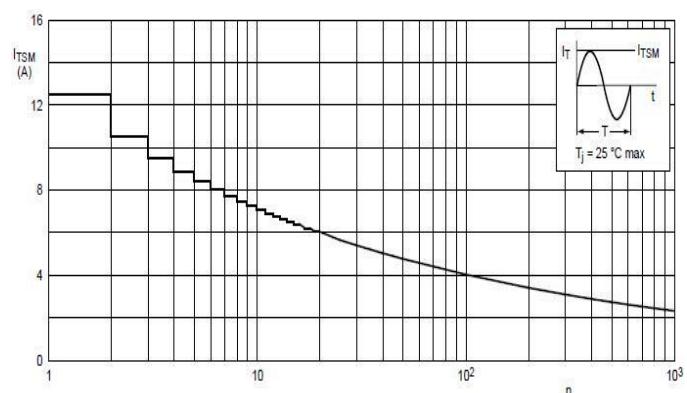
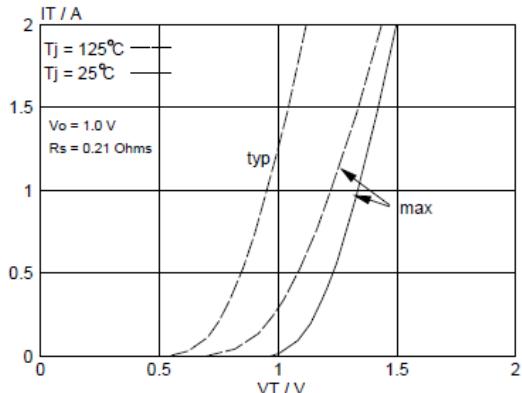
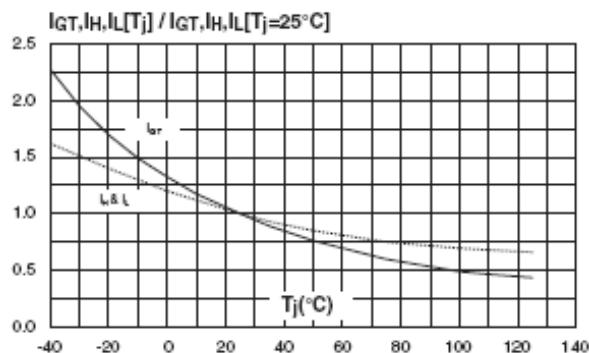
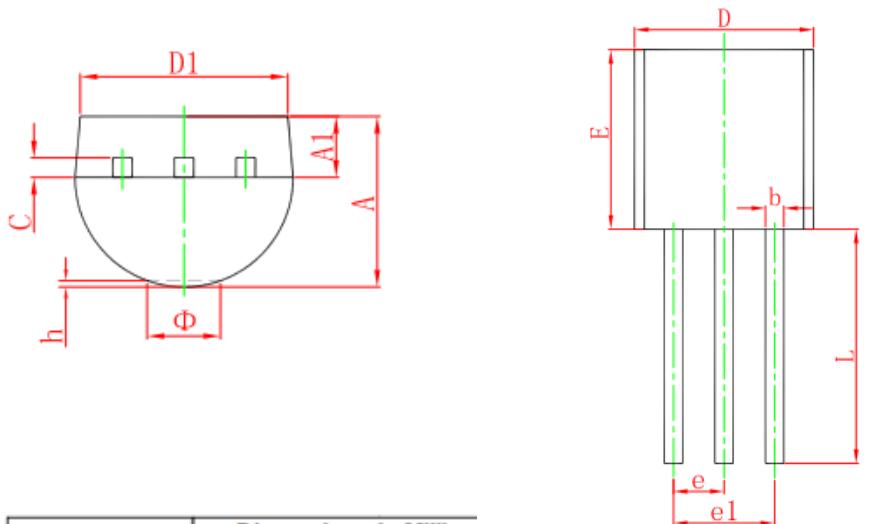


图5 IGT、IH、IL相对值（相对于25℃）与结温关系

Fig.5. Relative Variation Of Gate Trigger Current

, Holding Current And Latching Current Versus Junction Temperature (Typical Value)



封装尺寸 PACKAGE MECHANICAL DATA
TO-92


Symbol	Dimensions In Millimeters		Dimensions In Millimeters	
	Min.	Max.	Min.	Max.
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP.		0.050 TYP.	
e1	2.440	2.640	0.096	0.104
L	13.100	14.500	0.515	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

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